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## PAPER

## Two- and three-terminal far-from-equilibrium thermoelectric nano-devices in the Kondo regime

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## Abstract

This paper analyses the thermoelectric power of two- and three-terminal quantum dot devices under large thermal  $\Delta T$  and voltage  $V$  biases, and their performance as thermoelectric heat engines. The focus is on the interaction between electrons, far-from-equilibrium conditions, and strongly nonlinear transport, which all are important factors affecting the usefulness of the devices. To properly characterise the thermoelectric properties under such conditions, two different Seebeck coefficients are introduced, generalizing the linear response expression. In agreement with previous work, we find that the efficiency of the three-terminal thermoelectric heat engine, as measured by the delivered power, is optimal far from equilibrium. Moreover, strong Coulomb interactions between electrons on the quantum dot are found to diminish the efficiency at maximum power, and the maximal value of the delivered power, both in the Kondo regime and beyond.

## 1. Introduction

Thermoelectricity, the invention of the 19th century, is still at the forefront of research due to its importance for space exploration and automotive industry [1], and many more branches of modern technology both at large [2] and small [3] scales. Attempts to find high performance thermoelectric bulk materials [4], including those with topologically non-trivial [5] band structure, have seen limited progress. In the last few decades, a lot of attention has been put forward towards nano-devices [6] and molecular systems [7, 8], utilizing quantum effects to boost their thermoelectric performance towards the thermodynamic limit [9].

When a temperature gradient  $\nabla T$  (or a temperature difference  $\Delta T$ ) is established across a bulk material, a voltage  $V$  is generated. The response of an isotropic system is characterised by the Seebeck coefficient

$$S = -\left(\frac{V}{\Delta T}\right)_{I=0, \Delta T \rightarrow 0}, \quad (1)$$

defined under the condition of zero charge current. The same formal definition can be used for a nano-structure with two external electrodes [10] (see figure 1(a)). However, equation (1) has to be generalized for geometries with several electrodes—as, e.g. the one shown in figure 1(b)—where a whole matrix of Seebeck coefficients [11, 12] has to be introduced.

In bulk systems the linear approximation is generally a valid simplification. Under such a condition the thermoelectric figure of merit,  $ZT = GS^2T/\kappa$ , where  $G$  is the conductance, and  $\kappa$  the thermal conductance, is viewed as the most important factor deciding on the usefulness of the material as heat to electricity converter: namely, the efficiency is given by  $\eta = \eta_C(\sqrt{ZT+1} - 1)/(\sqrt{ZT+1} + 1)$ , where  $\eta_C$  is the Carnot value. In nanostructures containing quantum dots, however, we are virtually always dealing with a nonlinear situation, as mentioned earlier [13–15], and carefully discussed recently [6]. The small ratio of the sample length to the thermalization length in nanostructures is responsible for their very different behaviour compared to bulk systems. This has a profound effect on the analysis of small heat engines, and implies that the thermoelectric

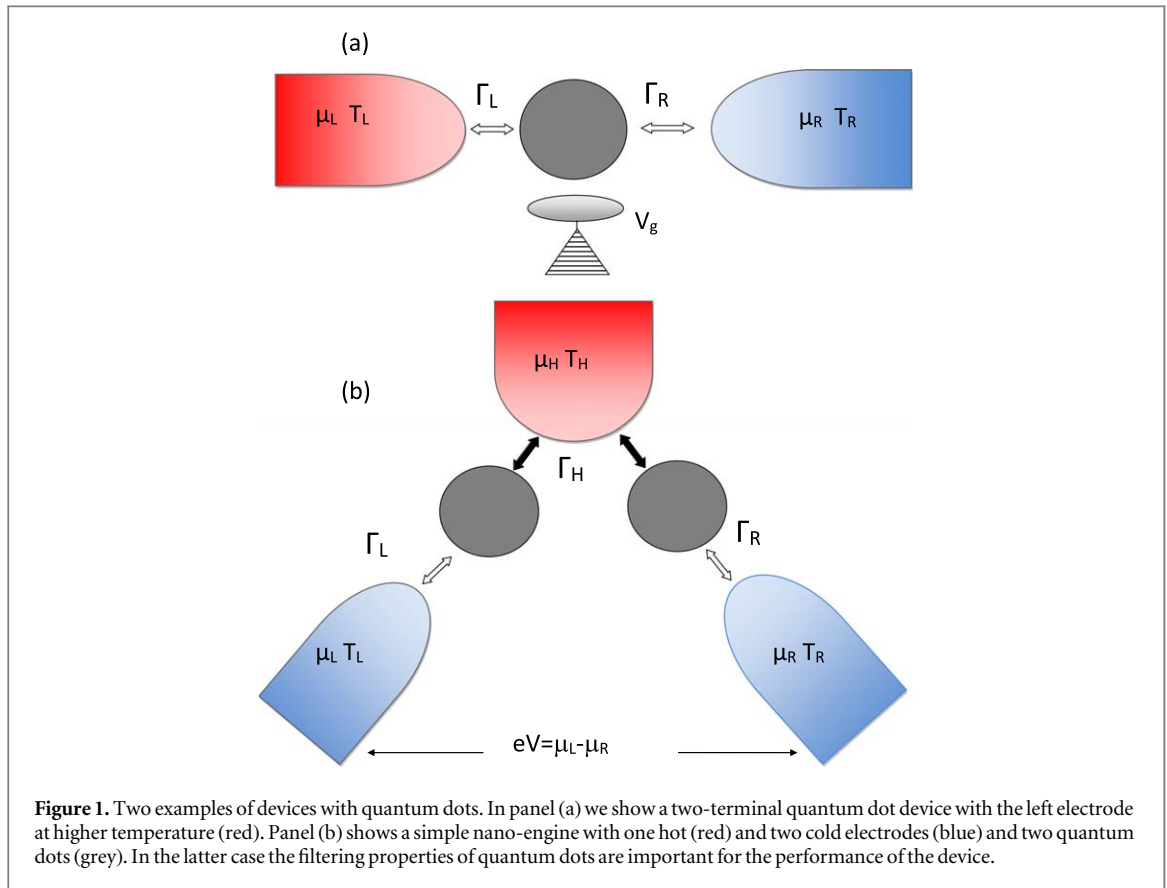


figure of merit  $ZT$  is not a useful parameter anymore to judge the efficiency. In particular, a nano-system with a large  $ZT$  [16] may in fact feature a small efficiency [17, 18].

From a basic point of view, the Seebeck coefficient provides additional and novel information about the studied system compared to that obtained from the electrical conductivity: the latter ‘measures’, in the simplest case, the density of states at the Fermi level,  $N(E_F)$ , and the former its slope,  $N'(E_F)$ . The thermopower can also be related to the entropy flowing between different parts of the system. In fact, the entropy of nano-systems has been recently measured [19] by means of thermoelectric transport. A strong increase of  $S$  in nano-devices and nano-structured materials has been observed [20], in agreement with the earlier proposal [21]. Recent studies [22] have shown that doping or nano-structuring bulk thermoelectric materials may lead to the required modifications of the energy spectrum close to  $E_F$ , but also to a localization of states which deteriorates the system’s performance.

Furthermore, it has been proposed [14, 23] that nonlinear working conditions can favourably affect the performance of heat engines. Recent studies in this direction include [24–29] and have been reviewed recently [30].

The aim of the present work is to study the thermoelectric transport of quantum dot based nano-devices by means of the non-equilibrium Green function approach, taking Coulomb interactions and nonlinear effects into account. In the nonlinear regime, more general definitions of the Seebeck coefficient than that given in equation (1) are needed; these are especially important when an externally applied voltage  $V$  is present while the system is thermally biased. In the presence of interaction and at low temperature, the Kondo effect is expected to dominate the transport properties [31–36]. The present investigation, which significantly extends our previous studies of non-equilibrium screening effects [37] in three-terminal two-quantum-dot heat engines [28, 38], is important for a better understanding of the interaction effects in far-from-equilibrium situations and in the Kondo regime.

As the theoretical treatment of an interacting quantum dot out-of-equilibrium is of importance in itself, we present in some detail the semi-analytical technique proposed by Lavagna [39]. It is based on the equation of motion method (EOM) [40] for the non-equilibrium (or Keldysh) Green functions [41], with important additions introduced by her which allow to properly describe the Kondo effect in the linear and the nonlinear regime, i.e. under large voltage and temperature differences between the electrodes, as well as for the particle-hole symmetric model. We shall discuss this in more detail at the end of the next section.

The use of the equation of motion (EOM) technique for studying the single-impurity Anderson model has a long history [42–44], mainly in the context of impurities in metals. Some of the attempts at generalizing the original EOM and the decoupling procedures have been summarized in [45].

The organization of the paper is as follows. In section 2 we present the model and our approach of calculating the charge and heat currents by means of the Keldysh non-equilibrium Green function (GF) technique. We also derive the exact—in the wide-band-limit—formula for the lesser GF. The resulting spectral function of the quantum dot is discussed in section 3 at low temperatures and for various conditions including particle-hole symmetry and non-equilibrium. Two relevant definitions of the Seebeck coefficients, valid in the nonlinear regime, are proposed and evaluated in section 4. The Coulomb interaction between electrons in the three-terminal quantum dot heat engine is found to diminish the performance of the device in question, as discussed in section 5. The Kondo effect shows up as a two-leaf structure of the performance diagram on the efficiency-power plane. Summary and conclusions are given in section 6.

## 2. Modelling the device and calculating currents

Here we discuss the simple geometry where the system consists of a quantum dot(s) tunnel-coupled to two (three) normal electrodes as shown in figure 1. The Hamiltonian of the system is written as

$$H = \sum_{\lambda,k,\sigma} \varepsilon_{\lambda k} n_{\lambda k \sigma} + \sum_{\sigma} \varepsilon_{\sigma} n_{\sigma} + U n_{\uparrow} n_{\downarrow} + \sum_{\lambda k \sigma} (V_{\lambda k \sigma} c_{\lambda k \sigma}^{\dagger} d_{\sigma} + V_{\lambda k \sigma}^{*} d_{\sigma}^{\dagger} c_{\lambda k \sigma}), \quad (2)$$

where  $n_{\lambda k \sigma} = c_{\lambda k \sigma}^{\dagger} c_{\lambda k \sigma}$  and  $n_{\sigma} = d_{\sigma}^{\dagger} d_{\sigma}$  denote particle number operators for the leads and the dot, respectively. The operators  $c_{\lambda k \sigma}^{\dagger} (d_{\sigma}^{\dagger})$  create electrons in respective states  $\lambda k \sigma (\sigma)$  in the leads  $\lambda = L, R, H$  (on the dot). The wave vector  $k$  denotes the Bloch state in the electrodes, the spin is  $\sigma = \pm 1$  ( $\uparrow, \downarrow$ ), and  $\varepsilon_{\sigma}$  is the generally spin-dependent dot electron energy level. For the concrete results presented in the next sections we will take  $\varepsilon_{\sigma}$  to be spin-independent,  $\varepsilon_{\uparrow} = \varepsilon_{\downarrow} = \varepsilon_d$ . The quantity  $V_{\lambda k \sigma}$  describes the tunneling of electrons from the dot to the electrode  $\lambda$ , and the Hubbard parameter  $U$  the repulsion between two electrons on the dot.

Calculations of the charge and heat currents flowing out of a given lead are standard [41]. Evaluating the required commutators one arrives at the expressions

$$I_{\lambda} = \frac{ie}{\hbar} \int \frac{dE}{2\pi} \sum_{\sigma} \Gamma_{\sigma}^{\lambda}(E) \{G_{\sigma}^{<}(E) + f_{\lambda}(E)[G_{\sigma}^r(E) - G_{\sigma}^a(E)]\}, \quad (3)$$

$$J_{\lambda} = \frac{ie}{\hbar} \int \frac{dE}{2\pi} \sum_{\sigma} \Gamma_{\sigma}^{\lambda}(E)(E - \mu_{\lambda}) \{G_{\sigma}^{<}(E) + f_{\lambda}(E)[G_{\sigma}^r(E) - G_{\sigma}^a(E)]\}. \quad (4)$$

The parameters  $\Gamma_{\sigma}^{\lambda}(E) = 2\pi \sum_k |V_{\lambda k \sigma}|^2 \delta(E - \varepsilon_{\lambda k})$  describe the coupling between the dot and the respective electrodes. The Green functions  $G_{\sigma}^i(E) = \langle \langle d_{\sigma} | d_{\sigma}^{\dagger} \rangle \rangle_E^i$  with  $i = r, a, <$  determine the spectral properties of the quantum dot as well as the transport properties of the whole system. Having in mind non-equilibrium transport induced by a voltage bias and/or a temperature difference, we keep the dependence of the Fermi distribution functions  $f_{\lambda}(E)$  on the electrode  $\lambda$  via its chemical potential  $\mu_{\lambda}$  and its temperature  $T_{\lambda}$ .

The important issue is the calculation of the lesser GF entering the above equations. In the literature various approximate schemes are used. Here, we show that in the steady state and in the wide-band approximation (i.e. for energy independent couplings:  $\Gamma_{\sigma}^{L,R}(E) = \Gamma_{\sigma}^{L,R}$ ), one can derive [39] the *exact* expressions for the lesser GF in terms of the retarded and advanced functions and thus closed formulas for the currents. First, from  $\langle n_{\sigma} \rangle = \langle c_{\sigma}^{\dagger}(t) c_{\sigma}(t) \rangle$  and the definition of the lesser GF, one has [41]

$$\langle n_{\sigma} \rangle = -i \int \frac{dE}{2\pi} G_{\sigma}^{<}(E). \quad (5)$$

The derivation then makes use of the fact that in the steady state

$$0 = \frac{d\langle n_{\sigma} \rangle}{dt} = \left\langle \frac{dn_{\sigma}}{dt} \right\rangle = - \left\langle \frac{i}{\hbar} [n_{\sigma}, H] \right\rangle. \quad (6)$$

Working out the commutator in (6), using (5) and the Langreth theorem [46], it is straightforward to derive the following ‘self-consistency’ condition [39]:

$$\langle n_{\sigma} \rangle = i \int \frac{dE}{2\pi} \frac{\Gamma_{\sigma}^L f_L(E) + \Gamma_{\sigma}^R f_R(E)}{\Gamma_{\sigma}^L + \Gamma_{\sigma}^R} [G_{\sigma}^r(E) - G_{\sigma}^a(E)]. \quad (7)$$

Let us underline again that the expression (7) is exact under the proviso that the couplings to the leads are energy independent,  $\Gamma_{\sigma}^{\lambda}(E) \equiv \Gamma_{\sigma}^{\lambda} = \text{const}$ . If this condition is violated, as it might be the case in graphene [47–49], hybrid systems with one (or both) of the electrodes being a superconductor, e.g. d-wave [50], other approaches are needed. For models with energy dependent couplings one still has to rely on approximate relations between the lesser self-energy  $\Sigma_{\sigma}^{<}(E)$  and the retarded one,  $\Sigma_{\sigma}^r(E)$ , making use of Ng’s approximation [51], a

generalisation of the fluctuation-dissipation theorem [24], or using the equation of motion for the lesser GF [52] and suitable decoupling. For recent attempts to include the energy-dependent couplings, see the paper [53].

Within the above (exact in the steady state and for constant  $\Gamma$ 's) formulation, the charge current across the two-terminal system can be written in terms of the retarded GF only:

$$I = \frac{2e}{\hbar} \sum_{\sigma} \tilde{\Gamma}_{\sigma} \int \frac{dE}{2\pi} [f_L(E) - f_R(E)] \text{Im } G_{\sigma}^r(E), \quad (8)$$

where  $\tilde{\Gamma}_{\sigma} = \Gamma_{\sigma}^L \Gamma_{\sigma}^R / (\Gamma_{\sigma}^L + \Gamma_{\sigma}^R)$ . We stress that the above formula is an exact representation of the current in terms of the retarded GF of the interacting Hamiltonian, which has to be calculated either numerically or analytically. Here we adopt the latter approach, though obviously calculating the GF analytically requires some approximations; see the supplementary material<sup>3</sup> for details. In brief, the decouplings we are using ensure that the GFs are formally exact up to second order in the couplings. Additionally, we correct the result by phenomenologically introducing the lifetimes [39] of various states, which is important to capture the Kondo effect. It turns out that the proposed scheme properly describes the Kondo resonance in the density of states even in the particle-hole symmetric model. The expression (8) is analogous to the well-known Meir–Wingreen formula [54]. One finds  $I = I_L = -I_R$  for the charge current, and  $\dot{Q} = J_L + J_R$  for the total heat current leaving the leads. For later use we define the power,  $P = (\mu_R - \mu_L)I/e$ , and the voltage bias,  $V = (\mu_R - \mu_L)/e$ , across the system.

Our general formulas for the charge and heat currents (4) are readily applied, e.g. to the three-terminal system shown in figure 1(b). In such a device, the heat is flowing from the hot to the two cold electrodes. We assume that no charge current flows out of or into the hot electrode. The charge flow is controlled by the gate bias of the quantum dots, which hence act as energy filters. The total heat current in the system is

$$J = J_H + J_L + J_R. \quad (9)$$

Introducing a ‘load’ between the two cold electrodes, in the figure (1) shown as an external voltage  $V$ , one finds the system’s energy harvesting efficiency as

$$\eta = \frac{IV}{J_H}. \quad (10)$$

To calculate currents we ‘only’ require the retarded Green function. There exist a few numerically exact approaches: e.g. among the many techniques applied to study the single-impurity Anderson model the quantum Monte Carlo [55] and the numerical renormalization group [56] methods should be mentioned. However, in this work we will use the analytic EOM technique, which has proven to be quantitatively correct [39, 57], and valid far from equilibrium. In addition, in our opinion this approach is physically more transparent than purely numerical methods, as discussed below.

After a couple of manipulations, the on-dot GF is obtained as follows:

$$\langle\langle d_{\sigma} | d_{\sigma}^{\dagger} \rangle\rangle_E = \frac{1 + I_d(E)[\langle n_{\bar{\sigma}} \rangle + b_{1\bar{\sigma}} - b_{2\bar{\sigma}}]}{E - \varepsilon_{\sigma} - \Sigma_{0\sigma} + I_d(E)[\Sigma_1^T + \Sigma_2^T - (b_{1\bar{\sigma}} - b_{2\bar{\sigma}})\Sigma_{0\sigma}]}, \quad (11)$$

where

$$I_d(E) = \frac{U}{E - \varepsilon_{\sigma} - U - \Sigma_{0\sigma} - \Sigma_{\sigma}^{(1)} - \Sigma_{\sigma}^{(2)}}. \quad (12)$$

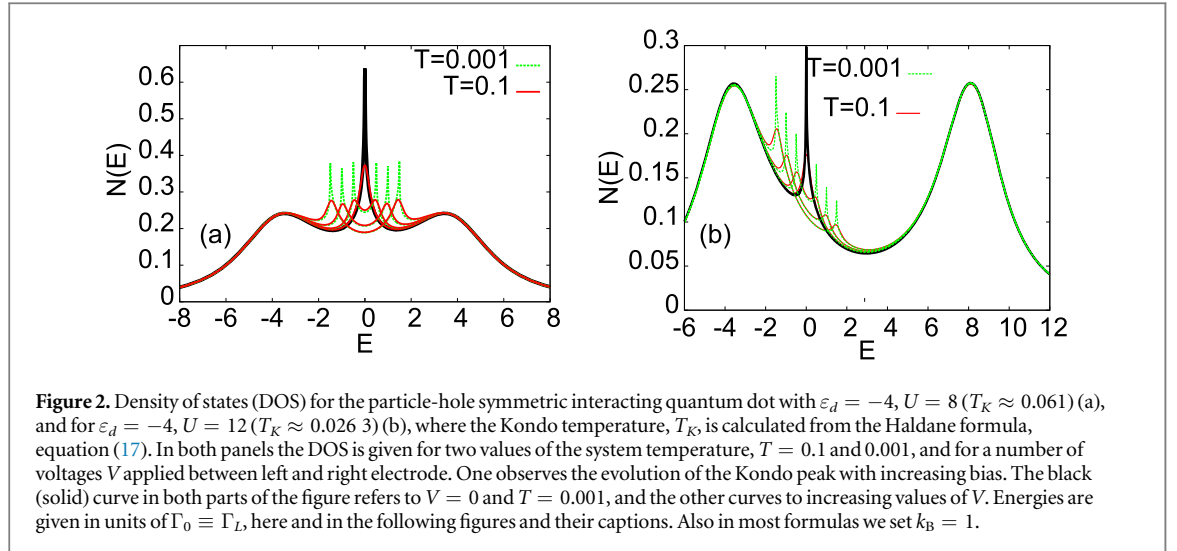
Details of the derivation and the definitions of the parameters are given in the Supplementary Material (See footnote 3). The above expression for the GF, equation (11), agrees with that obtained earlier by Lavagna [39].

It should be remembered that previous attempts to calculate the on-dot GF by means of the EOM technique encountered a serious problem. Namely, it was not possible to describe the Kondo resonance for the particle-hole symmetric system. Lavagna and co-workers [39, 57], however, have shown that for the correct description of the Kondo effect it is necessary to supplement the equations for the dot GF by two ingredients. First, one should introduce the finite lifetimes of singly and doubly occupied states on the dot. Second, it is important to include the many-body renormalization of the dot energy level  $\varepsilon_d$ . Thus, first, one replaces the  $E + i0$  terms in the definitions of various Green and correlation functions by  $E + i\tilde{\gamma}_{\alpha}$ , where the inverse lifetimes  $\tilde{\gamma}_{\alpha}$  of the excited states  $\alpha = |\sigma\rangle, |\uparrow, \downarrow\rangle$  are due to higher order processes. They can be calculated up to the desired order via the generalized Fermi rule as

$$\tilde{\gamma}_{\alpha} = 2\pi \sum_{|f\rangle} |\langle T(E_{\alpha}) \rangle|^2 \delta(E_{\alpha} - E_f), \quad (13)$$

with  $T(E) = \hat{V} + \hat{V}g(E)\hat{V} + \dots$  the scattering matrix, where  $\hat{V}$  denotes the part of the Hamiltonian describing the coupling between quantum dot and reservoirs. Second, one replaces  $\varepsilon_d$  by  $\tilde{\varepsilon}_d$ , to be calculated self-

<sup>3</sup> Supplementary material, available online at [stacks.iop.org/NJP/22/013045/mmedia](https://stacks.iop.org/NJP/22/013045/mmedia).



consistently from

$$\tilde{\varepsilon}_d = \varepsilon_d + \Sigma_1^T(\tilde{\varepsilon}_d) + \Sigma_2^T(\tilde{\varepsilon}_d). \quad (14)$$

The GF (11) has been shown to fulfil the unitarity limit, and to describe quantitatively correctly the Kondo effect [39] even in particle-hole symmetric systems in and out-of-equilibrium.

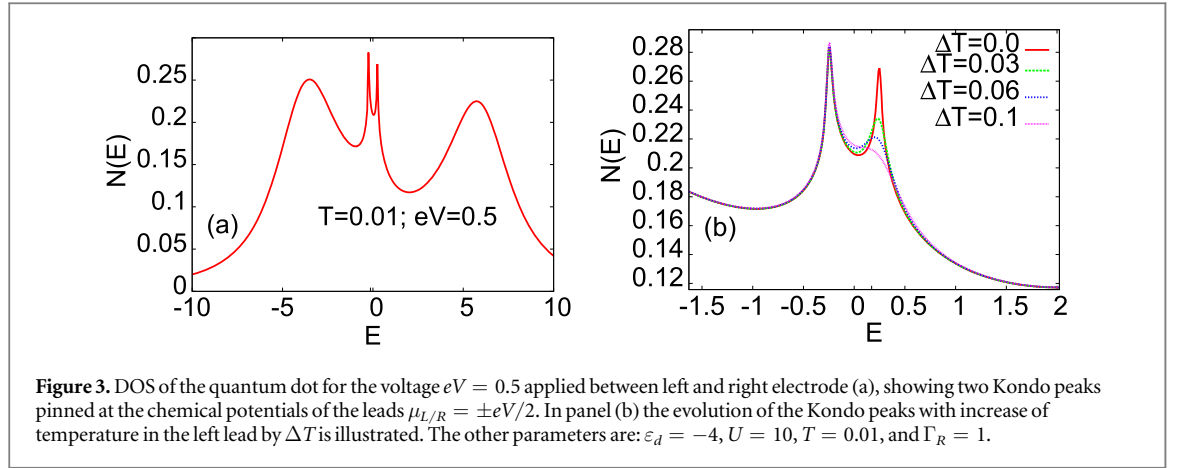
### 3. Kondo effect in equilibrium and far from equilibrium

For illustrative purposes and in order to introduce the framework, we discuss in this section the properties of an interacting quantum dot between two normal electrodes, as illustrated in figure 1(a). We start the presentation of the results by showing the density of states (DOS) of the quantum dot, which is calculated as usual as  $N(E) = -\sum_{\sigma} \text{Im} G_{\sigma}^r(E)/\pi$  from the retarded Green function, in various regimes. From now on, we neglect the spin dependence of the couplings, and slightly change the notation:  $\Gamma_{\uparrow}^L = \Gamma_{\downarrow}^L = \Gamma_L$ ,  $\Gamma_{\uparrow}^R = \Gamma_{\downarrow}^R = \Gamma_R$ . In addition, we measure all energies in units of  $\Gamma_0 \equiv \Gamma_L$ . The particle-hole symmetric case is of special importance as it is well known [39] that all previous attempts to use the EOM method failed in this case [58, 59]. The issue has been discussed extensively in the literature [43–45]; a critical comparison between EOM-based and other approximations has been presented very recently [60].

In figure 2 we present the DOS in the particle-hole symmetric situation with  $\varepsilon_d = -4\Gamma_0$  and  $U = 8\Gamma_0$ . Both lower and upper Hubbard bands centered in energy around  $\varepsilon_d$  and  $\varepsilon_d + U$  are clearly visible. At the same time, the Abrikosov–Suhl, sometimes also called Kondo resonance develops at the chemical potential.

The external bias shifts the chemical potentials of the leads  $\mu_{L/R} = \mu \pm eV/2$  to new positions, and the Kondo peak splits into two with each resonance pinned to the chemical potential of the lead. In particular, figure 2 shows the evolution of the two peaks with temperature. At  $T = 0.001\Gamma_0$ , they are very sharp, while at  $T = 0.1\Gamma_0$  they are reduced but still clearly visible. The changes of the Kondo resonance with bias and temperature are crucial to understand the behaviour of the thermally induced current and the (nonlinear) thermoelectric power as discussed in the next sections. At still higher temperatures (not shown) both Kondo peaks vanish altogether, and only lower and upper Hubbard bands survive. The Kondo resonance is due to spin flip processes on the dot while the Hubbard sub-bands are related to charge fluctuations. This explains the relative robustness of Hubbard sub-bands with increasing temperature, and the fragility of the Kondo correlations. However, voltage and temperature affect the Kondo resonance in a different way. While a voltage  $eV > T_K$  leads to a splitting of the resonance in two sub-peaks with concomitant decrease of their maximum, the finite temperature only lowers the height of the peak and broadens it. All these features are well reproduced by the used decoupling scheme. Outside the particle-hole symmetric point, the voltage-split Kondo resonances are not symmetric anymore. This is mainly due to the closer proximity of one of the resonances to the lower Hubbard band. The individual resonances are pinned to the Fermi levels of the respective electrodes. This is well visible in figure 2(b), and also in figure 3(a).

We now add a thermal bias to one of the electrodes, with focus on the question of how the density of states evolves with temperature difference. We start with the split Kondo resonance as shown in figure 3(a). The temperature of the right lead is kept constant, at  $T_R = T$ , while we gradually increase the temperature of the left electrode,  $T_L = T + \Delta T$ . Panel (a) of figure 3 shows the voltage-split Kondo peaks for  $\Delta T = 0$ , for easy



comparison, while panel (b) demonstrates the evolution of both peaks with increasing  $T_L$ . The peak pinned to the chemical potential of the left electrode (appearing at  $E = \mu_L$ ) is strongly affected by the temperature bias, it broadens and vanishes with increasing temperature. One observes only small changes of the other Kondo peak. Thus under voltage and temperature bias the peaks' heights and widths depend mainly on the conditions ( $V$ ,  $\Delta T$ ) at the electrode with the chemical potential to which it is pinned. For diminishing external voltage bias both peaks overlap in energy, and one observes a single feature in the density of states corresponding to the average temperature,  $T_{av} = (T_L + T_R)/2$ , of the system.

#### 4. Linear and nonlinear thermopower and the role of asymmetry

Nonlinear effects are expected to be important for many experiments on nano-devices [6, 15]. Hence in such cases alternative definitions of the thermoelectric coefficients are required. To start with, a suitable generalisation of the definition (1) of the Seebeck coefficient to nonlinear situations reads

$$S_n = -\left(\frac{V}{\Delta T}\right)_{I(\Delta T, V)=0}. \quad (15)$$

The traditional way to measure the Seebeck coefficient assumes the application of the temperature bias  $\Delta T$ , and finding the voltage  $V$  such that the current across the device vanishes,  $I(\Delta T, V) = 0$ . In this formulation, the only source of nonlinearity is directly given by the value of  $\Delta T$ , assumed to be large enough to preclude the linear expansion of the charge current  $I(\Delta T, V)$  in first powers of  $V$  and  $\Delta T$ .

On the contrary, when the linear expansion is valid,  $V \rightarrow 0$  and  $\Delta T \rightarrow 0$ , we have  $I(\Delta T, V) = L_{11}V + L_{12}\Delta T$ , and the corresponding thermopower is given by the ratio of kinetic coefficients,  $S = L_{12}/L_{11}$ . Expanding equation (8) for small  $V$  and  $\Delta T$  up to linear order, one finds an explicit expression for  $S$ .

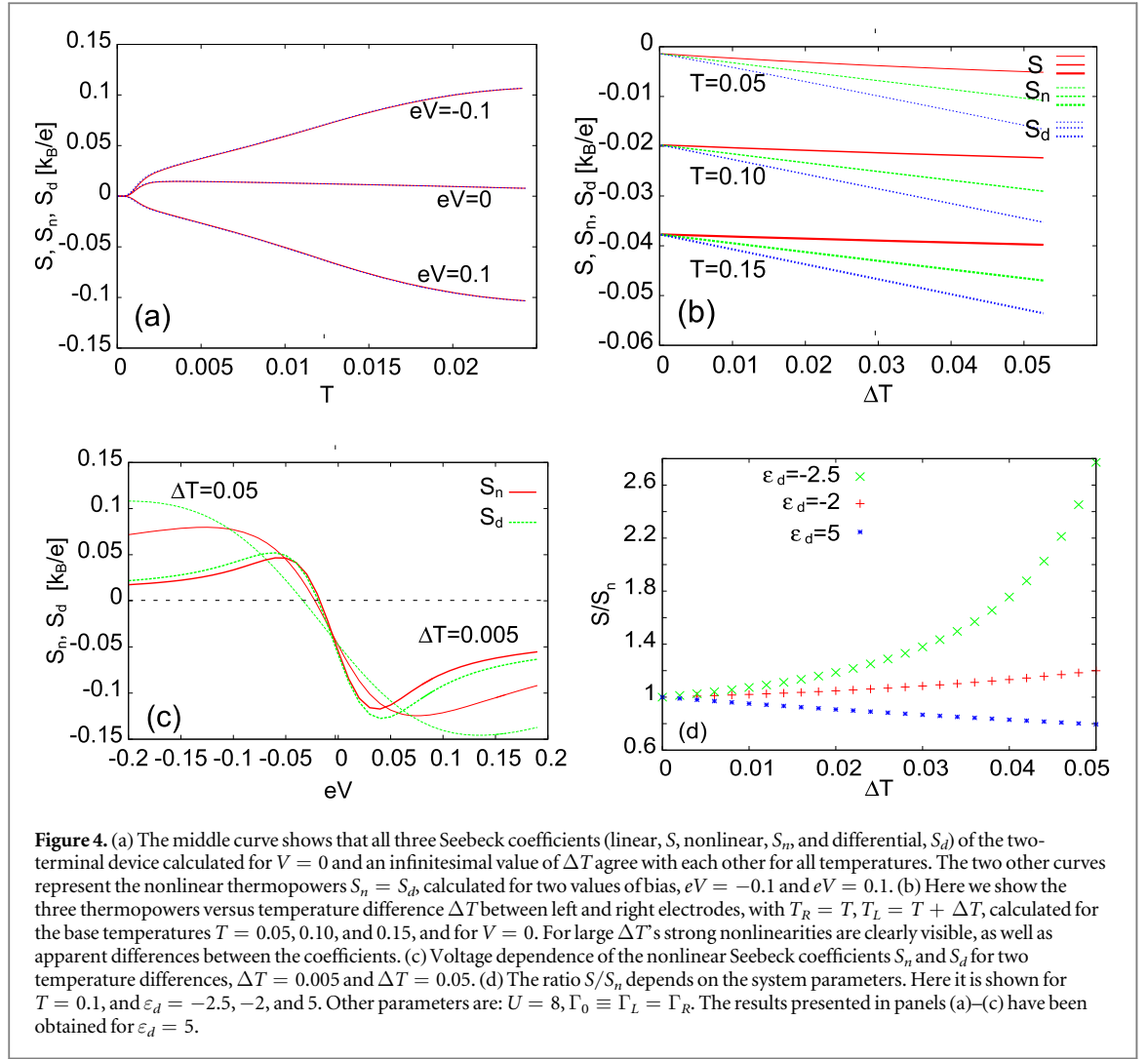
Sometimes the definition (15) of the nonlinear Seebeck coefficient  $S_n$  is extended to the differential one,  $S_d$ , calculated formally for constant current flowing as a result of the external voltage  $V$ . This  $S_d$  measures the response of the system with current flow to a minute change in temperature difference. At a given applied external voltage  $V$  and temperature difference  $\Delta T$ ,  $S_d$  is hence defined [31, 61] as

$$S_d = -\left(\frac{\partial V}{\partial \Delta T}\right)_I = -\left(\frac{\partial I}{\partial \Delta T}\right)_V / \left(\frac{\partial I}{\partial V}\right)_{\Delta T}. \quad (16)$$

As argued earlier,  $S_d$  should be accessible experimentally [31] in appropriate ac circuits. In that paper, the response  $(\partial I / \partial \Delta T)$  has been calculated under the additional assumption that, at a given external voltage, a very small temperature bias  $\Delta T$  is applied to the system. The definition (16) is analogous to the differential conductance  $G(V) = \partial I / \partial V$  often employed in the nonlinear regime.

Here we investigate the generalisation of  $S_d$  to arbitrary temperature differences and arbitrary bias as well as its comparison to  $S_n$  and  $S$ . Of course, for infinitesimally small  $\Delta T$  and  $V$  all definitions are equivalent and lead to the same result,  $S = S_n = S_d$ . For arbitrary  $V$  and  $T$  but vanishingly small  $\Delta T$ , the two nonlinear Seebeck coefficients are equal,  $S_n = S_d$ . However, for both a large  $\Delta T$  and a large bias voltage  $V$ , they differ, with the relative values depending on the parameters (see below).

To gain some feeling about the relative values and the behaviour of the three, generally different Seebeck coefficients, we show in figure 4 the linear,  $S$  (where appropriate), as well as the nonlinear,  $S_n$ , and the differential,  $S_d$ , coefficients as calculated for the two-terminal device. The panels (a)–(c) in figure 4 illustrate their



dependence on temperature, temperature difference, and voltage. We assume  $T_R = T$ ,  $T_L = T + \Delta T$ ,  $\mu_L = \mu + eV/2$ ,  $\mu_R = \mu - eV/2$ , and  $U = 8\Gamma_0$ ,  $\varepsilon_d = 5\Gamma_0$ . For  $U = 8\Gamma_0$  and  $\varepsilon_d = -5\Gamma_0$ , the Haldane formula for the Kondo temperature

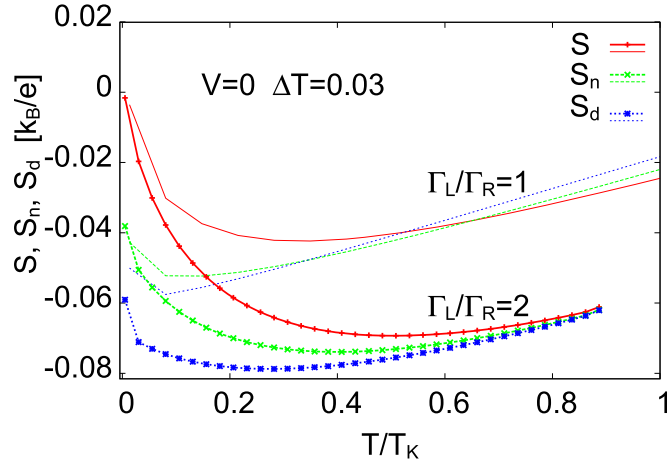
$$T_K = \frac{\sqrt{U\Gamma_N}}{2} \exp\left[\frac{\pi\varepsilon_d(\varepsilon_d + U)}{\Gamma_N U}\right], \quad \Gamma_N = \frac{\Gamma_L + \Gamma_R}{2}, \quad (17)$$

leads to  $T_K \approx 0.071\Gamma_0$ .

Figure 4(a) illustrates the  $T$ -dependence of all Seebeck coefficients for three values of the voltage  $eV = -0.1\Gamma_0, 0$ , and  $0.1\Gamma_0$ , and for a very small temperature difference,  $\Delta T \rightarrow 0$ . The value  $V = 0$  in fact denotes a very small voltage,  $V \rightarrow 0$ . For the actual calculations, we have used  $\delta T = 10^{-9}\Gamma_0$ , and to calculate the voltage derivative in (16) we have used  $\delta V = 10^{-9}\Gamma_0$ . All coefficients have the same value  $S = S_n = S_d$  for  $V \rightarrow 0$ . For a relatively large value of  $V$ , the calculation of  $S$  is meaningless; the figure shows that independent of  $T$  and for both values of  $V$  one has  $S_n = S_d$  (since the applied temperature difference is infinitesimal).

The situation is different if  $\Delta T$  is finite. The results for  $V = 0$  are presented in figure 4(b); it is apparent that all coefficients assume different values, except for very small  $\Delta T$ . The differences increase with increasing  $\Delta T$ , with  $S_d$  lying below  $S_n$  (and  $S_n$  below  $S$ ) for all  $T$  and a given set of parameters.

For finite voltages the relative order of  $S_n$  and  $S_d$  may be different, as is visible from panel (c) of the figure. The Seebeck coefficient  $S_n$  provides a generalisation of the standard definition to the nonlinear regime, while the differential one,  $S_d$ , characterises the response to a minute temperature change of the voltage biased system. The data presented in figure 4(c) have been obtained for  $T = 0.01\Gamma_0$ , and the two values  $\Delta T = 0.005\Gamma_0$  and  $0.05\Gamma_0$ . For small temperature bias the curves corresponding to  $S_n$  and  $S_d$  are rather close to each other. However, for larger  $\Delta T$  the nonlinear dependence of the Fermi functions and the on-dot density of states on  $V$  and  $\Delta T$  lead to various contributions to both  $S_n$  and  $S_d$ .



**Figure 5.** The anisotropy of the couplings  $\Gamma_R/\Gamma_L \neq 1$  results in increased absolute values of the Seebeck coefficients. We show all three coefficients, albeit the temperature difference  $\Delta T = 0.03$  is slightly beyond the validity of the linear approximation. Other parameters of the model read:  $U = 8$ ,  $\varepsilon_d = -5$ . The Kondo temperature is  $T_K \approx 0.004$  for the symmetric case,  $\Gamma_R/\Gamma_L = 1$ , and  $\approx 0.034$  for  $\Gamma_R/\Gamma_L = 2$ .

It has to be underlined that  $S$  can be smaller or larger than  $S_n$ , depending on the system parameters. For example, for  $\varepsilon_d = -2.5\Gamma_0$ ,  $T = 0.1\Gamma_0$ , and other parameters as in figure 4(d), we have  $|S| > |S_n|$ , with the difference increasing with  $\Delta T$ . It is also apparent that for  $\varepsilon_d = 5\Gamma_0$  the ratio is smaller than one, i.e. for these parameters the linear thermopower happens to be smaller than the nonlinear one.

The non-zero value of both Seebeck coefficients  $S_n$  and  $S_d$  for  $V = 0$  in figure 4(c) can be understood by taking into account the lack of particle-hole symmetry,  $2\varepsilon_d + U \neq 0$ , for the set of parameters used. For these parameters the density of states is similar to that shown in panel (b) of figure 2. The differences between the curves  $S_n(V)$  and  $S_d(V)$  for the same  $\Delta T$  are of the same character as those observed in figure 4(b), while the global similarities between the two sets of curves calculated for  $\Delta T = 0.005\Gamma_0$  and  $\Delta T = 0.05\Gamma_0$  can be traced back to a larger contribution to  $(\partial I/\partial \Delta T)$  obtained from equation (8):

$$\left(\frac{\partial I}{\partial \Delta T}\right) \approx -\frac{2e}{\hbar} \sum_{\sigma} \tilde{\Gamma}_{\sigma} \int \frac{dE}{2} \left\{ [f_L(E, T) - f_R(E, T)] \left( \frac{\partial N(E, T, \Delta T)}{\partial \Delta T} \right) - N(E, T, \Delta T) \left( -\frac{\partial f_L(E)}{\partial \Delta T} \right) \right\} + O((\Delta T)^2) + \dots \quad (18)$$

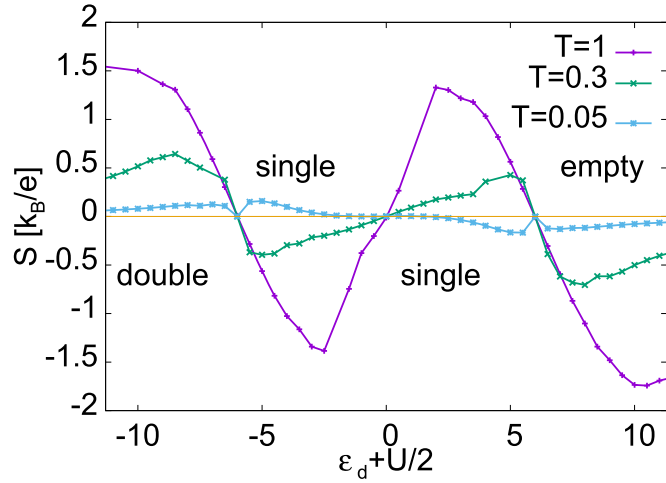
Note that the difference

$$D(V) = [f_L(E, T) - f_R(E, T)] = -D(-V) \quad (19)$$

is an odd function of the voltage, which implies that the resulting curves are nearly anti-symmetric with respect to  $V = 0$  (and that the ordinates are equal,  $S_n(0) \approx S_d(0)$ ). The smaller contribution proportional to  $(-\partial f_L(E)/\partial \Delta T)$  depends on  $V$  in a non-universal way. This causes the crossing of two coefficients at various voltages and for  $\Delta T$  well beyond the validity of the linear approximation.

We remark that the differential Seebeck coefficient,  $S_d$ , has been analysed in [31, 61]; in particular, the authors claim that  $S_d$  allows for a better understanding of decoherence processes at finite voltage. Indeed, as observed in figure 3(b), the decoherence processes at finite voltage  $V$  are mainly induced by the increase of temperature at one of the electrodes. These processes are most effective at energies around the chemical potential of the hotter electrode. It follows from our calculations of  $S_d$ , which is typically larger than  $S$ , that measuring the thermopower under a finite voltage and sensing the temperature at the same time may be challenging, as the current flow (over-)heats the system. In fact, overheating of a metallic quantum dot has been observed in recent measurements of the thermovoltage in a two-terminal device [62], despite the open circuit ( $I = 0$ ) condition.

We note that the asymmetry of the couplings  $\Gamma_L \neq \Gamma_R$  also affects the Seebeck coefficients. To see this, we assume  $V = 0$  and a relatively small temperature difference  $\Delta T = 0.03\Gamma_0$ . Figure 5 shows  $S$ ,  $S_n$ , and  $S_d$  calculated for symmetric coupling (thin lines) as well as for an asymmetric system with  $\Gamma_R/\Gamma_L = 2$  (thick lines). Interestingly, the largest decrease of the Seebeck coefficient is observed at low temperatures, well below the Kondo temperature, in agreement with recent findings [61] based on the non-crossing approximation. The Seebeck coefficient has a minimum at temperatures below  $T_K$ , and the minimum is lower for the asymmetric



**Figure 6.** Linear Seebeck coefficient ( $S$ ), calculated for three temperatures  $T = 1, 0.3$ , and  $0.05$ , versus  $\varepsilon_d + U/2$  which measures the distance from the particle-hole symmetric point. The interaction parameter is  $U = 12$ , and  $\Gamma_L = \Gamma_R$ . The indicated occupancy of the level  $\varepsilon_d$  depends on the gate voltage.

coupling. The asymmetry of the couplings is an important experimental observation [63], and should be taken into account in any calculation comparing with experiment [64].

The experiment mentioned above [62] has shown the usefulness of the nonlinear Seebeck coefficient for the analysis of the experimental data. The authors have directly measured the thermovoltage  $V_{th}$  of a two-terminal device, similar to that shown in figure 1(a), however, for a sizable metallic island. In order to compare experimental data with theory,  $V_{th}$  was calculated as  $S \cdot \Delta T$ : notably, the agreement can be improved (details depending on parameters) when using the nonlinear expression [62], i.e. the calculated  $S_n$  instead of  $S$ . The remaining disagreement is likely due to heating. In this context, it may also be useful to employ the differential coefficient,  $S_d$ . However, a detailed quantitative comparison with experimental results is beyond the scope of this paper, since, *inter alia*, the model investigated here likely is too simplified compared to the metallic islands actually studied.

Our theory also allows to explain the results shown in figure 4(a) of a recent experimental paper [29], albeit with a notable exception. These authors have found ‘striking’ sign changes of the Seebeck coefficients, in addition to the standard sign change at the particle-hole symmetric point. These sign changes depend on the spin configuration of the quantum dot and are observed with increasing temperature. In the experiment [29],  $S$  in fact changes sign at three values of the gate voltage, with one of them at the particle-hole symmetric point. Two other gate voltages at which sign changes appear are related to consecutive energy levels crossing the chemical potential.

In our theory for the single-level quantum dot, the sign change is observed when one of the resonance levels  $\varepsilon_d$  or  $\varepsilon_d + U$  crosses the Fermi level in response to the gate voltage. In order to describe this effect, we have calculated the linear Seebeck coefficient for  $U = 12\Gamma_0$ , and for three different temperatures, see figure 6. One sees that the Seebeck coefficient vanishes not only at the particle-hole symmetric point,  $\varepsilon_d + U/2 = 0$ , but also at the points  $\varepsilon_d + U/2 = -6\Gamma_0$  and  $\varepsilon_d + U/2 = 6\Gamma_0$ . In the range  $\varepsilon_d + U/2 > -6\Gamma_0$ ,  $S$  is positive for low  $T$  but negative for elevated temperatures. For the considered value of  $U = 12\Gamma_0$ , and for a gate voltage such that  $\varepsilon_d + U/2 = -6\Gamma_0$ , the doubly occupied level  $\varepsilon_d + U$  just crosses the chemical potential (located at zero energy) from below. This implies that at this gate voltage the system crosses over from double to single occupancy. A similar situation is observed to the left of  $\varepsilon_d + U/2 = 6\Gamma_0$ , when the level  $\varepsilon_d$  crosses the Fermi energy and the occupancy changes from single occupation to empty with increasing  $\varepsilon_d + U/2$  from below to above  $6\Gamma_0$ .

The vanishing of the high temperature thermopower at these two points in our approach results from the perfect symmetry of the dot density of states around the Fermi energy for the corresponding two gate voltages. At very low temperature, the Kondo effect sets in and we are getting very deep minima when  $\varepsilon_d$  or  $\varepsilon_d + U$  cross the chemical potential, while experiment shows a local maximum of the thermopower at these points for  $T < T_K$ . We emphasise that the typical asymmetry of the Kondo peak outside the particle-hole symmetry point is well reproduced by the present approach. The experimental data in figure 4(a) in [29], on the other hand, seem to show only positive (or negative), i.e. finite values of  $S$  around those special points at the lowest temperatures, with an apparent maximum (minimum) at the gate voltage where the theoretical Seebeck coefficient has a dip (peak).

In this context, we also wish to mention the experimental results presented by Svilans *et al* [65], which for zero magnetic field are essentially very similar to our findings (figure 6). The experimental results are analysed theoretically in [66] with focus on the field dependence, employing the numerical renormalisation group (NRG) method. While this technique is numerically exact, it is limited to linear response. In particular, the NRG method provides a maximum of  $S$ , in agreement with experiment, where our elaborated EOM technique predicts a dip. Seemingly, the NRG characterises the Kondo state better than the EOM method.

### 5. Three-terminal thermoelectric heat engine: the role of strong Coulomb interactions

As already noted, a thermoelectric device can serve as waste heat to electricity converter. Since energy harvesting is an important issue at large and small scales, its proper understanding may have important scientific and societal implications. As discussed in the Introduction, the figure of merit,  $ZT$ , ceases to be a good quality indicator in nanostructures [13, 15], and both the power and the efficiency are required. The quantities of interest are the maximum power, and the efficiency at maximum power. As it turns out the interactions between electrons strongly modify all transport characteristics. In the present model, the linear response calculations generally lead to lower values of  $\eta/\eta_C$  than those obtained from the fully self-consistent results, to be described in the following. However, in both cases the interactions tend to diminish the maximal power and the efficiency.

The focus of this section is on the effects of strong interactions between the on-dot electrons on the performance characteristics of the three-terminal heat engine shown in figure 1(b). For the non-interacting case but well outside equilibrium, such a device has been studied earlier [28, 38]. A more recent extension takes screening effects into account, treating the interactions within a mean-field approximation [37]. The main conclusion was that albeit the screening modifies the parameters at which the engine is optimal, it does neither change the maximal power nor the efficiency at maximum power. A similar heat engine has also been optimised with respect to the transmission function [67].

In particular, we have found [37] that the three-terminal heat engine at optimised conditions attains an efficiency slightly above 0.2 in units of the Carnot efficiency, and that this value is roughly the same as the one without screening effects. The optimisation involved the effective coupling between the dots and the leads,  $\Gamma/T_{av}$ , the temperature difference between the electrodes,  $\Delta T/T_{av}$ , and the load voltage,  $V$ ;  $T_{av}$  denotes the average temperature of the system. (The coupling  $\Gamma$  introduced here refers to the symmetric case with  $\Gamma_L = \Gamma_R = \Gamma_H \equiv \Gamma$  [37]). The calculations have shown that the optimal coupling, i.e. the one leading to the maximal power if other parameters remain fixed, is of the order of the average temperature,  $\Gamma/T_{av} \approx 1$ . The efficiency has been found to depend rather weakly, and the power strongly on the temperature difference  $\Delta T$  between the hot ( $H$ ),  $T_H = T + \Delta T$ , and the two cold ( $R, L$ ) electrodes,  $T_R = T_L = T$ .

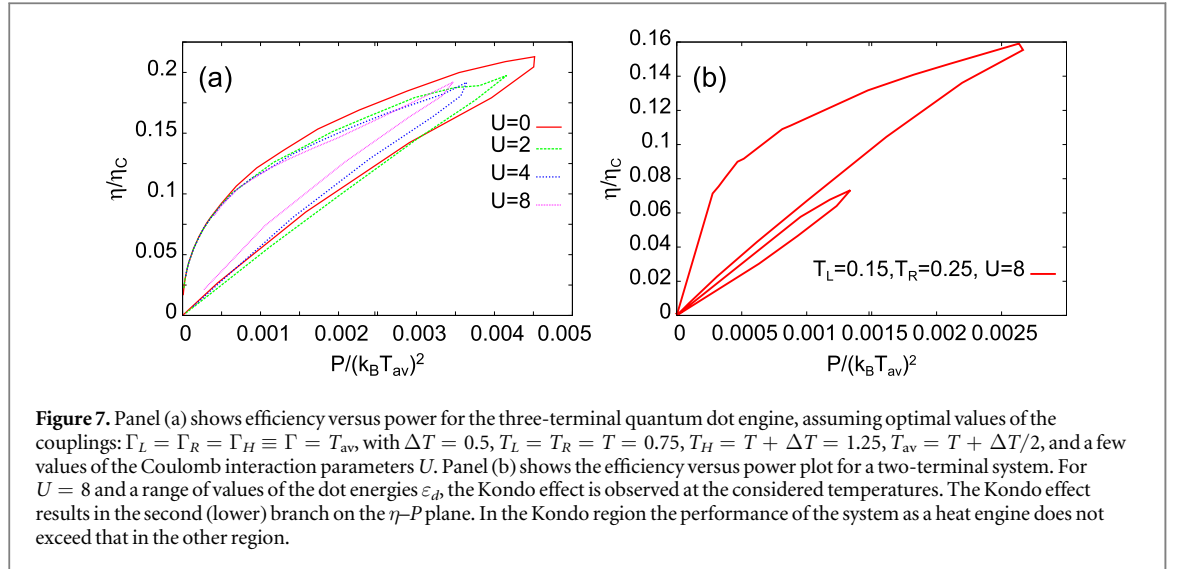
Here we shall pursue the analysis assuming nonlinear working conditions and taking strong interactions into account. In particular, the calculations include the Kondo regime. To this end, we use the general expressions (3) for the charge and (4) for the heat current flowing out of the  $\lambda$  lead, energy conservation, and the general expression (11) for the on-dot Green function. From the charge current flowing from the left to the right electrode, and the heat current flowing from the hot to the cold electrodes, we calculate the performance of the engine as quantified by the maximum power  $P$ , and the efficiency  $\eta$  at maximum power.

In order to demonstrate the effect of the Coulomb interaction on the performance of the engine, we show in figure 7 the efficiency  $\eta$  versus power  $P$ . The efficiency is measured in units of the Carnot efficiency,  $\eta_C = \Delta T/T_H = 0.4$ , and the power is normalized by  $(k_B T_{av})^2$ . The plot shown in panel (a) has been obtained by calculating the heat and charge currents as well as the optimal voltage (and the power) for a given difference of the dot's energy levels,  $\Delta E = \varepsilon_R - \varepsilon_L$ , where  $\varepsilon_R$  ( $\varepsilon_L$ ) refers to the energy level of the right (left) dot, see figure 1. Note that for appropriate values of  $\varepsilon_R$  ( $\varepsilon_L$ ) and low temperature, the respective dot may show Kondo behaviour. This has an important effect on the  $\eta$ - $P$  plot.

In panel (a) of figure 7 one sees that the  $U = 0$  curve essentially encompasses all curves obtained for the interacting case. Coulomb interactions generally suppress the performance characteristics—at least so under the assumptions of the present approach, including the wide-band approximation. The temperature of all electrodes are such that this system (figure 7(a)) is always outside the Kondo regime.

To illustrate the behaviour of an engine working in the Kondo regime, we show in figure 7(b) a similar plot, but obtained for a two-terminal system and a much lower value of the average temperature. For the interaction  $U = 8\Gamma_0$ , and temperatures  $T_L = 0.15\Gamma_0$ ,  $T_R = 0.25\Gamma_0$ , the dot enters the Kondo regime for a range of gate voltages (or  $\varepsilon_d$ ). The Kondo effect results in the appearance of the new performance branch on the  $\eta$ - $P$  plane. As visible in panel (b) of the figure, this region is characterised by efficiencies and powers lower than those outside the Kondo regime.

The results shown in figure 7 have been obtained under the assumption that the couplings to the leads equals the average temperature,  $\Gamma = T_{av}$ , the value which has been found to be optimal (i.e. leading to the maximal



power) for the non-interacting system. Analogous to [37], we change the dots' energy levels, thereby varying the difference  $\Delta E = \varepsilon_R - \varepsilon_L$ , and calculate the power and efficiency for each  $\Delta E$  for the optimised value of the load voltage  $V$ . The curves in figure 7 are thus parametrised by  $\Delta E$ .

Regarding the experimental situation, very recently a three-terminal two-quantum-dot system identical to the three-terminal system studied here has been found [68] to generate a power of 0.13 fW, its efficiency being estimated to be larger than  $\eta \approx 0.1\eta_C$ . To find the actual values of the device power, we need the width of the resonance level,  $\Gamma$ . Assuming  $\Gamma = 0.15$  meV (which is the average value of those mentioned in figure 4 of [68]), we find that the maximal power in figure 7(a) equals 3.92 fW. The corresponding estimate of the power at the efficiency  $\eta/\eta_C = 0.1$  gives  $P = 0.44$  fW, in good agreement with the experimental value, taking into account the uncertainty in estimating  $\Gamma$ , its non-optimal value in the actual experiment, and a possible asymmetry of the couplings. In fact, the maximal efficiency we obtain, for optimised parameters, is slightly above 0.2 of the Carnot value.

## 6. Summary and conclusions

We have studied the thermoelectric transport properties of two- and three-terminal systems with quantum dots, paying attention to strong interactions of electrons on the dot(s) and far-from-equilibrium conditions. As theoretical tool, we have used the suitably generalised equation of motion technique. We have shown that the method is able to capture the Kondo resonance even for a system with particle-hole symmetry. The voltage across the system splits the resonance. Interestingly, the increase of the temperature of one of the electrodes affects the Kondo resonance pinned to the chemical potential of that electrode. This adds to the discussion of decoherence effects in non-equilibrium conditions. It turns out that the decoherence mainly takes place at energies close to the chemical potential of the electrode with temperature higher than the Kondo temperature.

Of particular importance is the nonlinear regime at large external voltage bias  $V$  and large temperature difference  $\Delta T$ , since the linear approximation is hardly ever valid in nanostructures. This has been again confirmed here, and is visible as the detrimental effect of strong correlations on the performance of the three-terminal optimised heat engine. Calculating the maximum power  $P$  and the efficiency  $\eta$  of the optimised device for various interactions  $U$ , we have observed that except at very low temperatures the curves calculated for  $U \neq 0$  are encompassed by the curve obtained for the non-interacting system. Obviously the filtering properties of the quantum dots are affected by the interactions which broaden or split the density of states, rendering the filter less effective. This agrees with previous attempts at optimising heat engines by engineering the transmission function [23, 67]. On the other hand, strong interactions are responsible for the second leaf on the efficiency versus power plane, visible in figure 7(b). This special feature appears at low temperatures when the system enters the Kondo regime, albeit for a relatively small range of gate voltages. However, the maximum values of  $P$  and  $\eta$  are well below those on the main branch.

The generalisation of the standard linear-response Seebeck coefficient,  $S$ , to the strongly nonlinear regime has led us to define two coefficients,  $S_n$  and  $S_d$ , cf equations (15) and (16). Both are, in principle, valid for arbitrary values of  $V$  and  $\Delta T$ , albeit the first coefficient,  $S_n$ , is easier to handle in systems with zero external voltage but arbitrarily large temperature difference between a given pair of electrodes. The second, called differential Seebeck coefficient, has been applied earlier [31, 61] to systems with finite current flow and a small

temperature difference. It has been generalized and studied here for arbitrary  $\Delta T$  in the presence of an external voltage bias  $V$ . Interestingly, the asymmetry of the couplings to the external leads has a qualitatively similar influence on both Seebeck coefficients. They develop a minimum for temperatures well below the Kondo temperature. The observed quantitative differences between  $S_n$  and  $S_d$  are expected to be important for temperature sensing by means of thermopower measurements [69].

The approach developed in this work has significantly enhanced the understanding of non-equilibrium thermal transport through quantum-dot based devices, in particular, it has the potential to describe the existing as well as future experiments on such systems.

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